



V

V

I_D

Part Number	Package	Marking
HGP230N10A	TO-220	GP230N10A

Absolute Maximum Ratings at T_i

	Symbol		Unit
		31	A
		100	V
Gate to Source Voltage	V _{GS}	20	
Pulsed Drain Current	I _{DM}	100	
Avalanche Energy, Single Pulse	E _{AS}	20	mJ
Power Dissipation	P _D T _C	52	
Operating and Storage Temperature	T _J , T _{stg} -	-55 to 175	

Absolute Maximum Ratings

Parameter	Symbol	Max	Unit
Thermal Resistance Junction-Case	R	2.9	
Thermal Resistance Junction-Ambient	R	60	



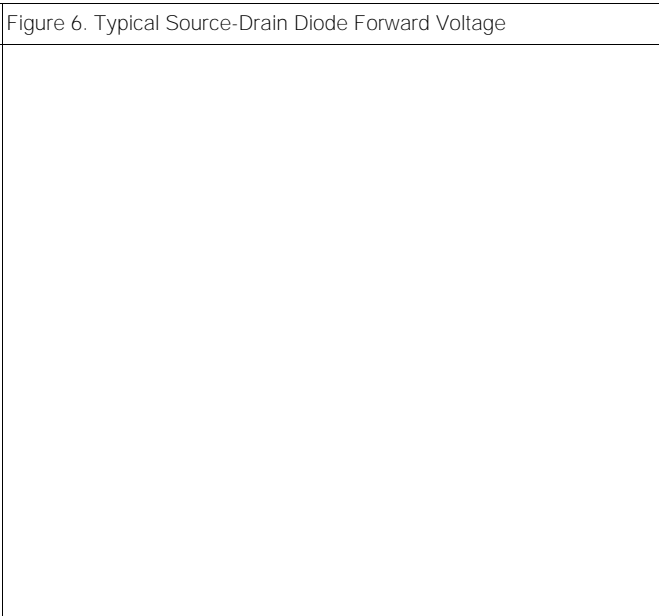
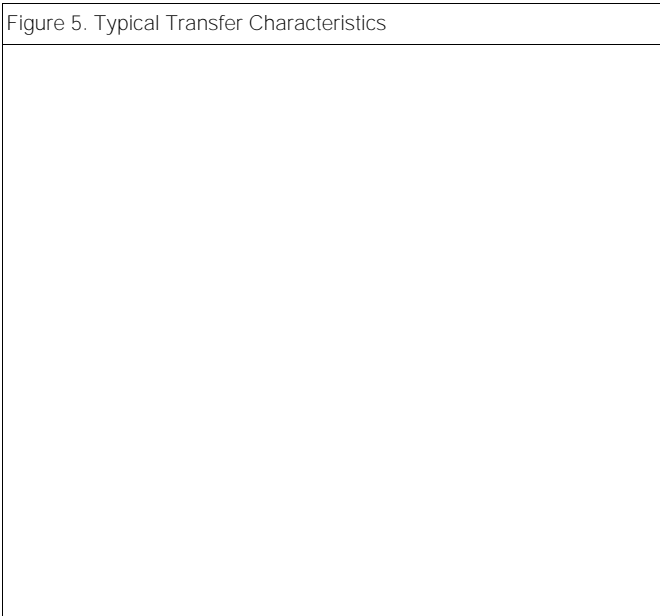
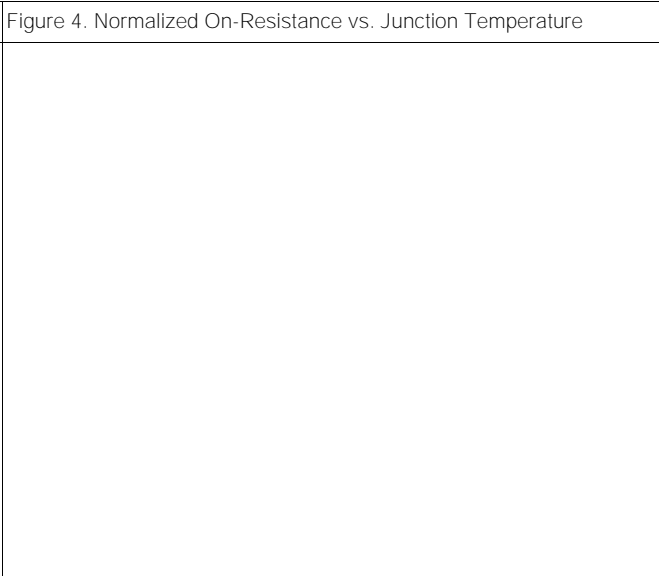
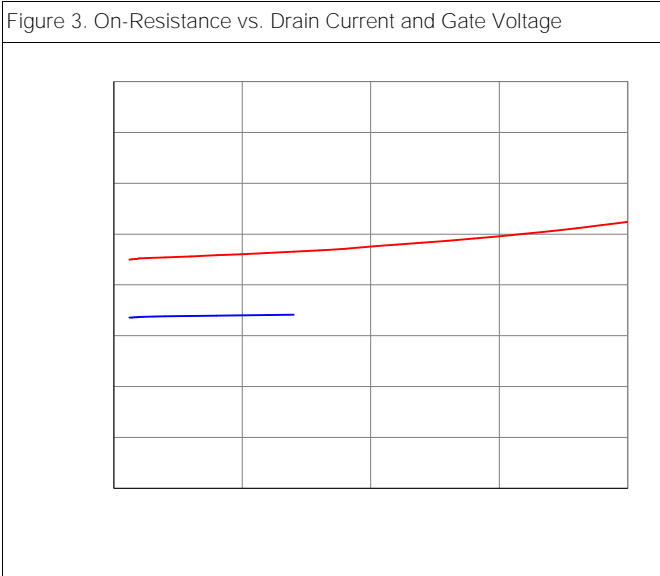
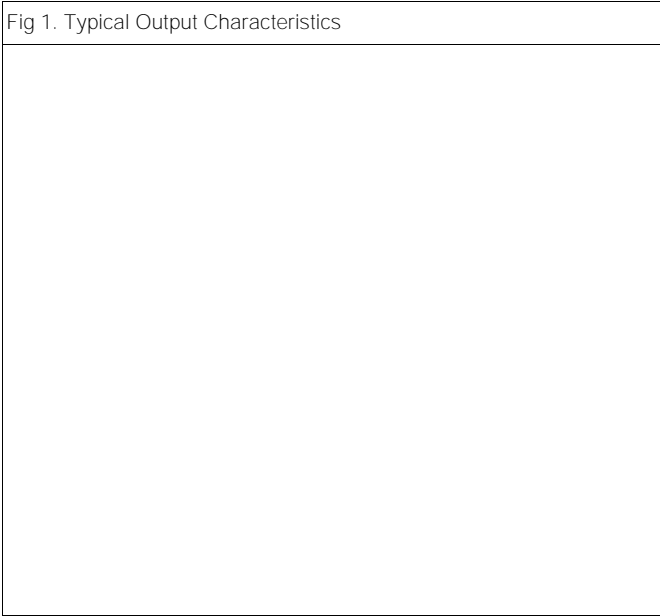


Figure 7. Typical Gate-Charge vs. Gate-to-Source Voltage

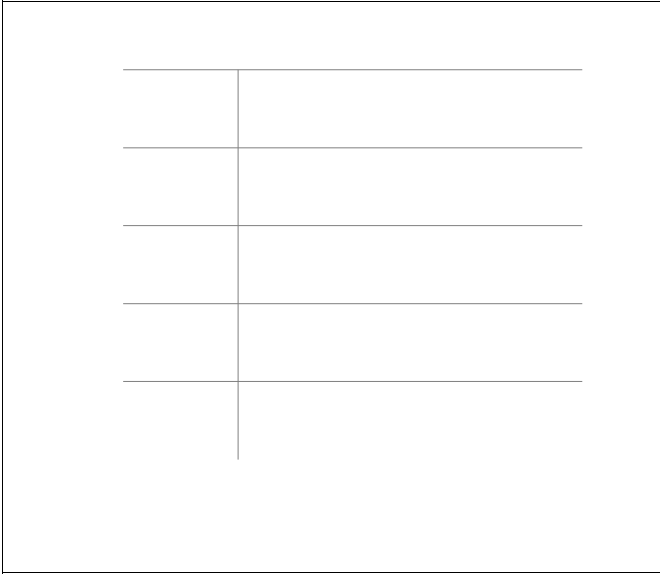


Figure 8. Typical Capacitance vs. Drain-to-Source Voltage

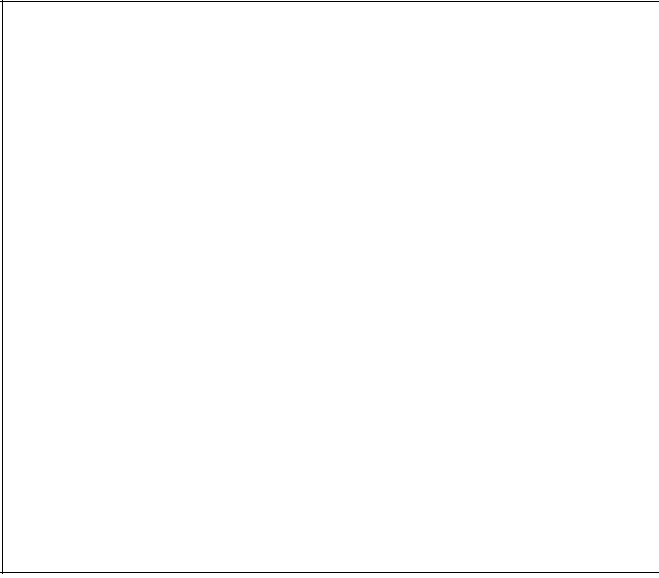


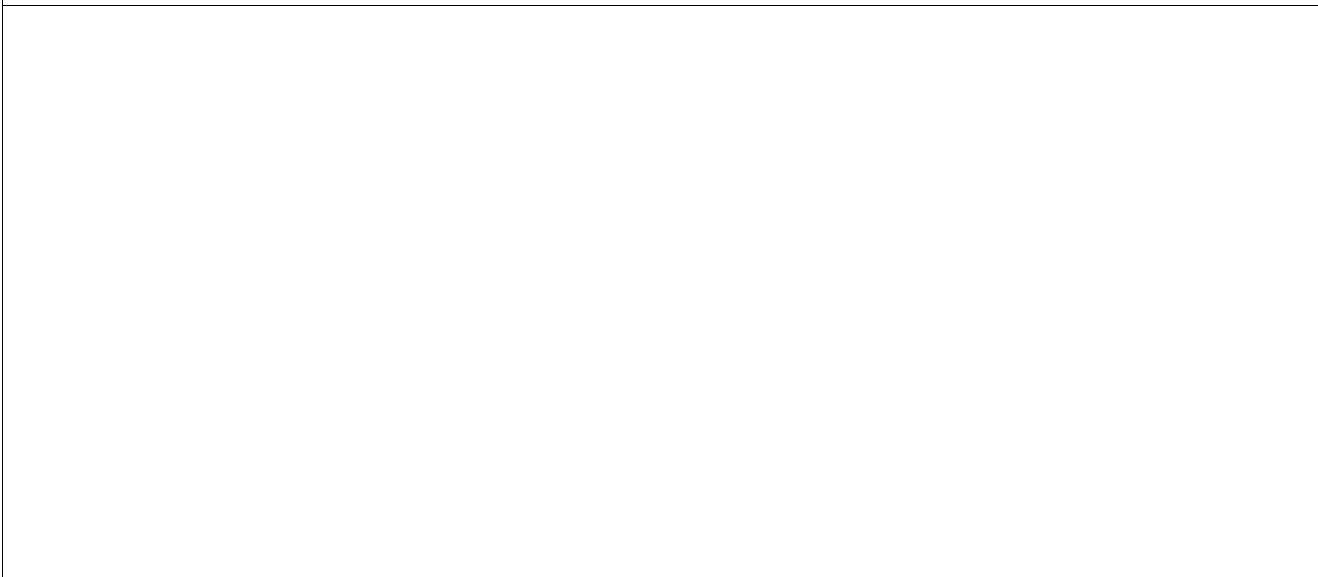
Figure 9. Maximum Safe Operating Area



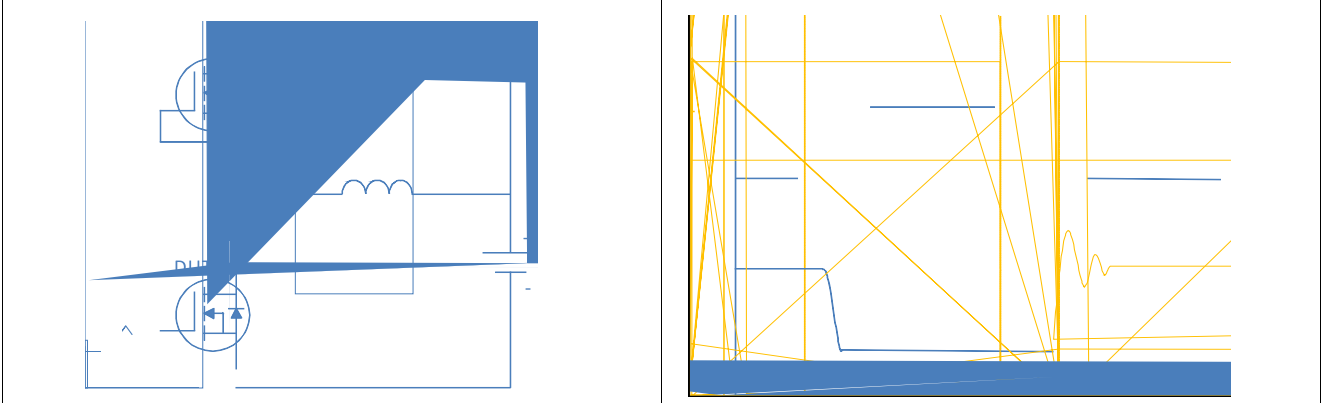
Figure 10. Maximum Drain Current vs. Case Temperature



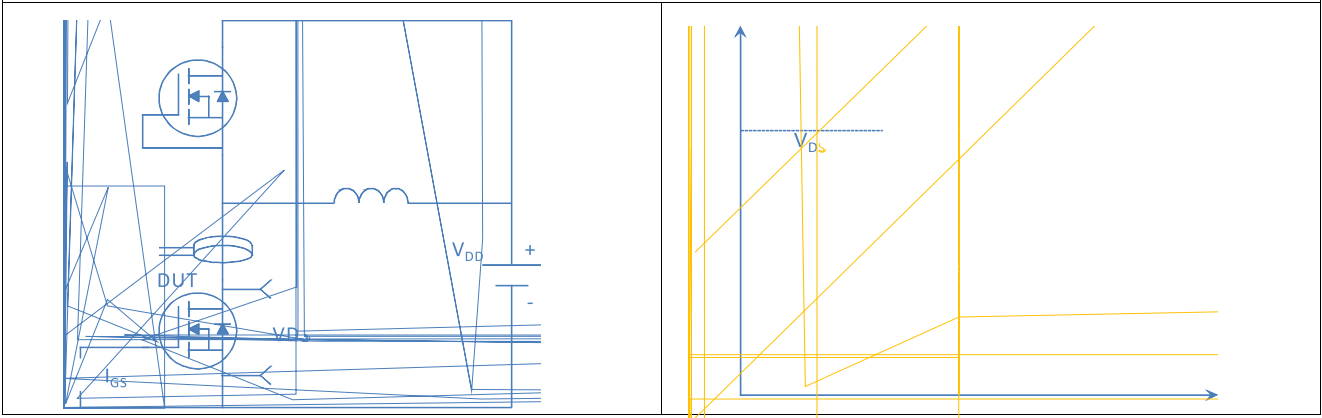
Figure 11. Normalized Maximum Transient Thermal Impedance, Junction-to-Case



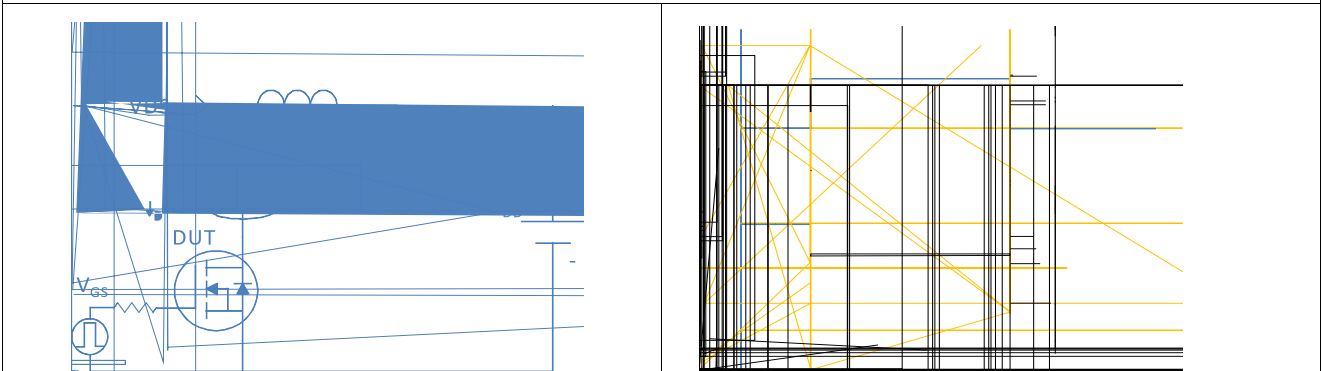
Inductive switching Test



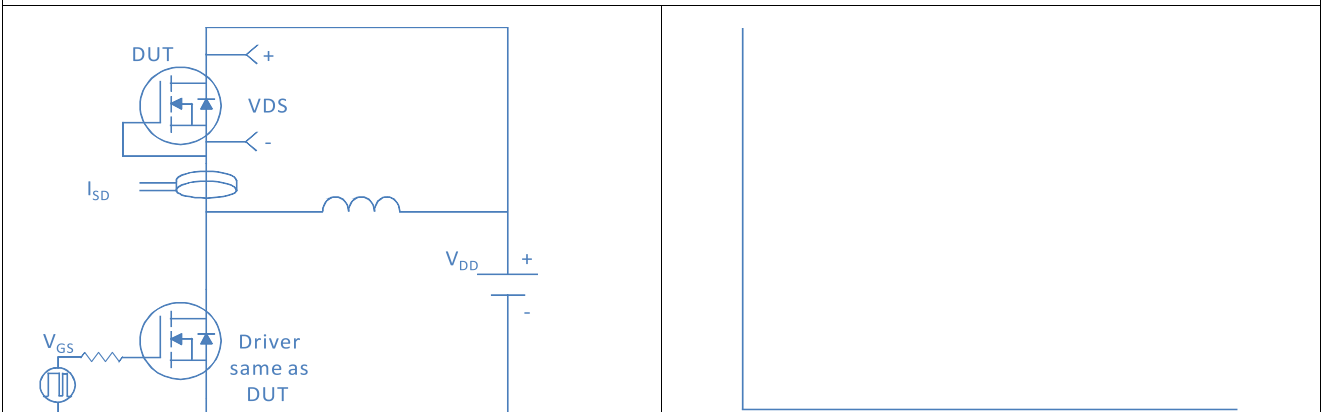
Gate Charge Test



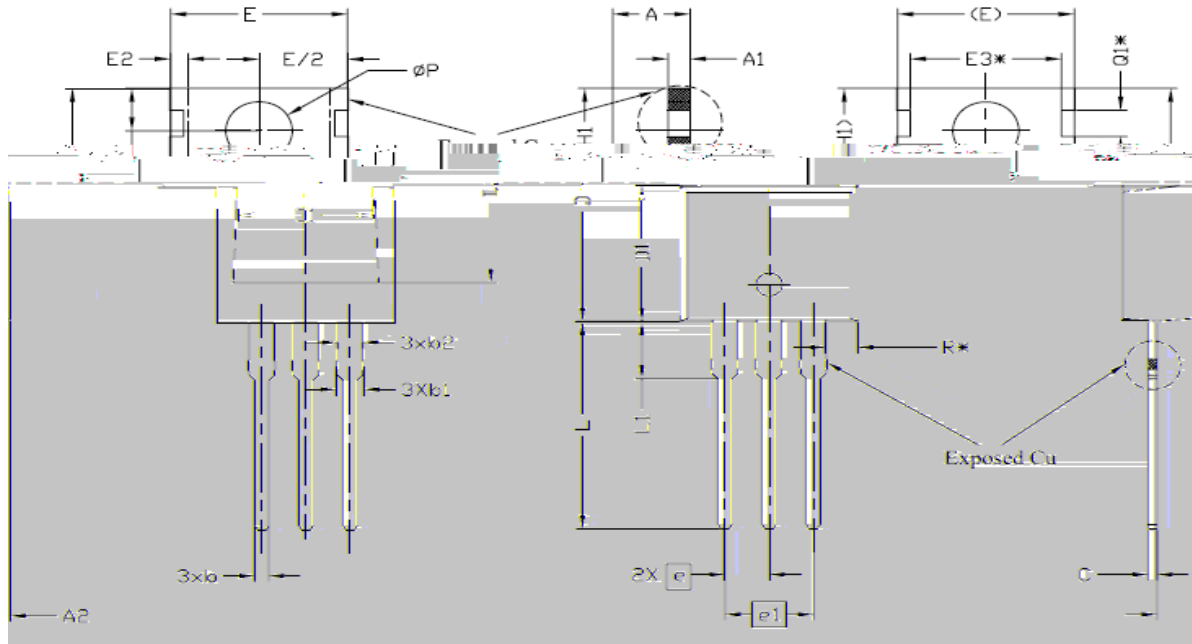
Uclamped Inductive Switching (UIS) Test



Diode Recovery Test



TO-220, 3 leads



SYMBOL	DIMENSIONS			NOTES
	MIN.	NOM.	MAX.	
A	4.24	4.44	4.64	
A1	1.15	1.27	1.40	
A2	2.30	2.48	2.70	
b	0.70	0.80	0.90	
b1	1.20	1.55	1.75	
b2	1.20	1.45	1.70	
c	0.40	0.50	0.60	
D	14.70	15.37	16.00	4
D1	8.82	8.92	9.02	
D2	12.63	12.73	12.83	5
E	9.96	10.16	10.36	4,5
E1	6.86	7.72	8.89	5
E2	-	-	0.76	6
E3*	8.70REF.			
e	2.54BSC			
e1	5.08BSC			
H1	6.30	6.45	6.60	5,6
L	13.47	13.72	13.97	
L1	3.60	3.80	4.00	
øP	3.75	3.84	3.93	
Q	2.60	2.80	3.00	
Q1*	1.73REF.			
R*	1.62REF.			